Vishay Semiconductors

High Speed Infrared Emitting Diodes, 850 nm, Surface Emitter Technology



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DESCRIPTION

As part of the <u>SurfLight</u>^{IM} portfolio, the VSMY2853 series are infrared, 850 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

APPLICATIONS

- IrDA compatible data transmission
- Miniature light barrier
- Photointerrupters
- Optical switch
- Emitter source for proximity sensors
- IR touch panels
- IR illumination
- 3D TV

FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.55
- Peak wavelength: $\lambda_p = 850 \text{ nm}$
- High reliability
- High radiant power
- · Very high radiant intensity
- Angle of half intensity: $\phi = \pm 28^{\circ}$
- · Suitable for high pulse current operation
- Terminal configurations: gullwing or reverse gullwing
- Package matches with detector VEMD2503X01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

PRODUCT SUMMARY					
COMPONENT	l _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)	
VSMY2853RG	35	± 28	850	10	
VSMY2853G	35	± 28	850	10	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMY2853RG	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing	
VSMY2853G	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing	

Note

• MOQ: minimum order quantity

Pb-free



(5-2008)





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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	А	
Power dissipation		Pv	190	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +85	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	acc. figure 7, J-STD-020	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, soldered on PCB	R _{thJA}	250	K/W	

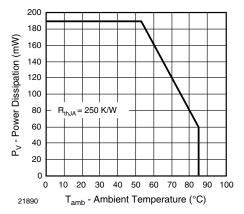


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

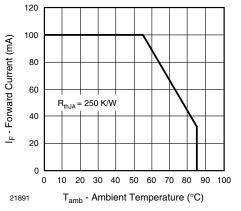


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.65	1.9	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F		2.9		V
Temperature coefficient of V_F	I _F = 1 mA	TK _{VF}		-1.45		mV/K
	I _F = 10 mA	TK _{VF}		-1.3		mV/K
Reverse current		I _R	not designed for reverse operation		μA	
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0 mW/cm^{2}$	CJ		125		pF
	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	20	35	50	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l _e		300		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе		55		mW
Temperature coefficient of radiant power	I _F = 100 mA	ΤΚφ _e		-0.35		%/K
Angle of half intensity		φ		± 28		deg
Peak wavelength	I _F = 100 mA	λp	840	850	870	nm
Spectral bandwidth	I _F = 30 mA	Δλ		30		nm
Temperature coefficient of λ_p	I _F = 30 mA	ΤΚλ _p		0.25		nm/K
Rise time	$I_F = 100 \text{ mA}, 20 \% \text{ to } 80 \%$	tr		10		ns
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		10		ns

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

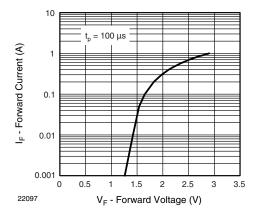


Fig. 3 - Forward Current vs. Forward Voltage

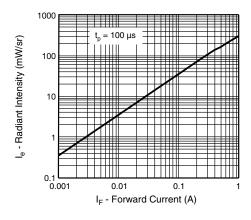


Fig. 4 - Radiant Intensity vs. Forward Current

SOLDER PROFILE

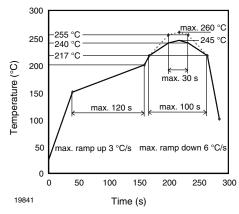


Fig. 7 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

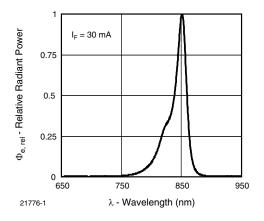


Fig. 5 - Relative Radiant Power vs. Wavelength

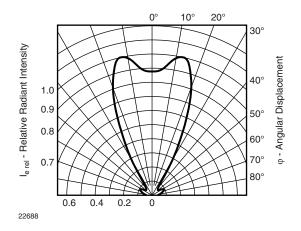


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 4 weeks

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 2a, acc. to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

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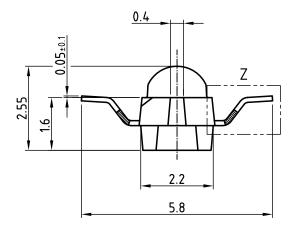


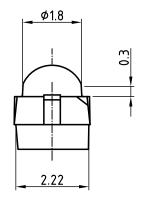


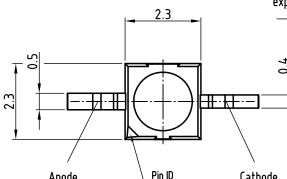
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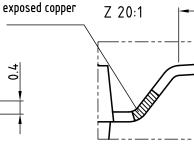
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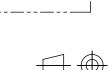
PACKAGE DIMENSIONS in millimeters: VSMY2853RG





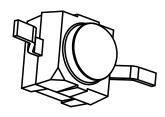




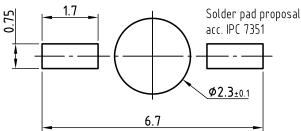


technical drawings according to DIN specifications

Dimensions in mm Not indicated tolerances ±0.2



Pin ID Anode Cathode



Drawing refers to following types:

VSMY2853RG

Drawing-No.: 6.544-5409.03-4 Issue: prel. 03.08.12

Rev. 1.2, 27-Mar-14

Document Number: 83480

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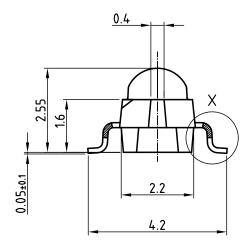
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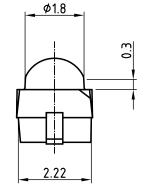
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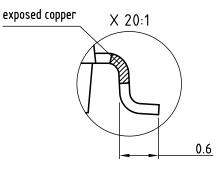


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PACKAGE DIMENSIONS in millimeters: VSMY2853G

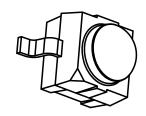


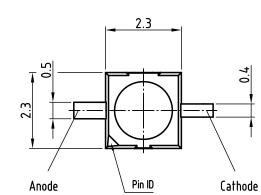


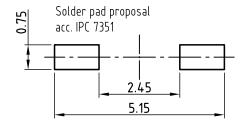




Dimensions in mm Not indicated tolerances ±0.2



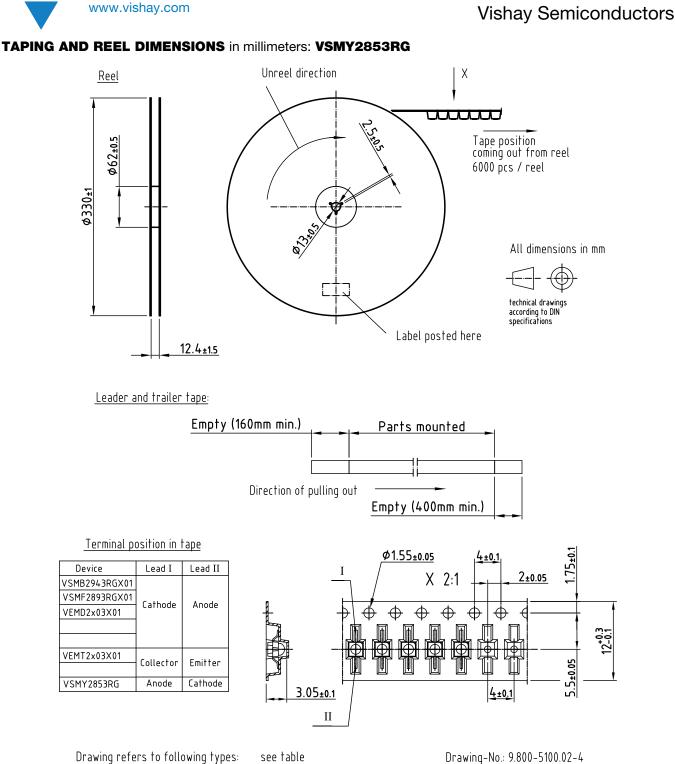




Drawing refers to following types:

VSMY2853G

Drawing-No.: 6.544-5408.03-4 Issue: prel; 03.08.12



Issue: prel; 03.08.12

VSMY2853RG, VSMY2853G

Reel dimensions and tape

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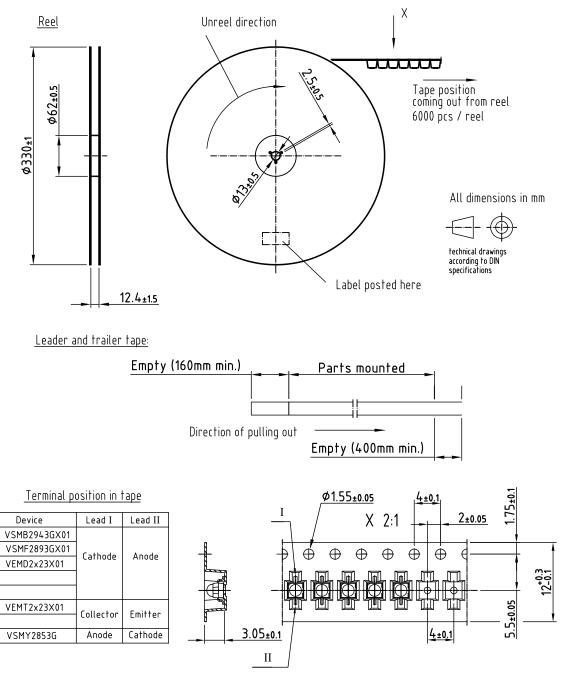
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TAPING AND REEL DIMENSIONS in millimeters: VSMY2853G



Drawing refers to following types: see table Reel dimensions and tape Drawing-No.: 9.800-5091.21-4 Issue: prel; 03.08.12

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